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Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier





PRIMARY CHARACTERISTICS				
I _{F(AV)}	3 A			
V _{RRM}	120 V			
I _{FSM}	60 A			
V _F at I _F = 3 A (125 °C)	0.61 V			
T _J max.	175 °C			
Package	SlimSMAW (DO-221AD)			
Circuit configuration	Single			

FEATURES

- Low-profile package
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C



RoHS

COMPLIANT HALOGEN

FREE

- AEC-Q101 qualified available
 Automotive ordering code: base P/NHM3
- Compatible to SOD-128 package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, DC/DC converters, and polarity protection in commercial, industrial, and automotive applications.

MECHANICAL DATA

Case: SlimSMAW (DO-221AD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

H3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	VSS8D3M12	UNIT		
Device marking code		3M12			
Maximum repetitive peak reverse voltage	V _{RRM}	120	V		
Maximum average forward restified averant (fig. 1)		3	^		
Maximum average forward rectified current (fig.1)	I _{F(AV)} ⁽²⁾	2	A		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	60	А		
Operating junction temperature range	ction temperature range T _J ⁽³⁾ -40 to +175		℃		
Storage temperature range	T _{STG}	-55 to +175			

Notes

(1) Mounted on 30 mm x 30 mm AL PCB pad area

⁽²⁾ Free air, mounted on recommended copper pad area

⁽³⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{0JA}$



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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 1.5 A	T _A = 25 °C	V _F ⁽¹⁾	0.61	-	- V
	$I_F = 3 A$			0.75	0.83	
	I _F = 1.5 A	- T _A = 125 °C		0.52	-	
	I _F = 3 A			0.61	0.69	
Reverse current	V _R = 90 V	T _A = 25 °C	_R (2)	0.01	-	mA
	v _R = 90 v	T _A = 125 °C		0.5	-	
	V _R = 120 V	T _A = 25 °C		-	0.3	
	v _R = 120 v	T _A = 125 °C		1	4	
Typical junction capacitance	4.0 V, 1 MHz		CJ	310	-	pF

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)					
PARAMETER	SYMBOL	TYP.	MAX.	UNIT	
Typical thermal resistance	R _{0JA} (1)(2)	120	150	°C/W	
	R _{0JM} ⁽³⁾	12	15	C/W	

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint

⁽³⁾ Thermal resistance junction-to-mount to follow JEDEC 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
VSS8D3M12-M3/H	0.033	Н	3500	7" diameter plastic tape and reel		
VSS8D3M12-M3/I	0.033	I	14 000	13" diameter plastic tape and reel		
VSS8D3M12HM3/H ⁽¹⁾	0.033	Н	3500	7" diameter plastic tape and reel		
VSS8D3M12HM3/I ⁽¹⁾	0.033	I	14 000	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

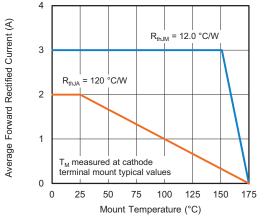


Fig. 1 - Maximum Forward Current Derating Curve

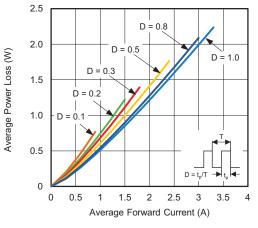


Fig. 2 - Forward Power Loss Characteristics

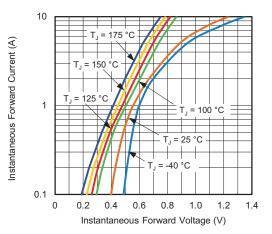


Fig. 3 - Typical Instantaneous Forward Characteristics

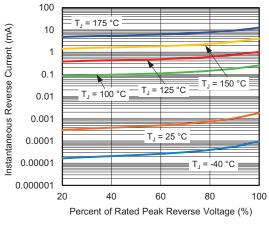


Fig. 4 - Typical Reverse Leakage Characteristics

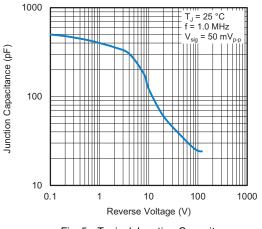


Fig. 5 - Typical Junction Capacitance

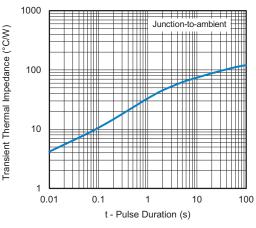


Fig. 6 - Typical Transient Thermal Impedance

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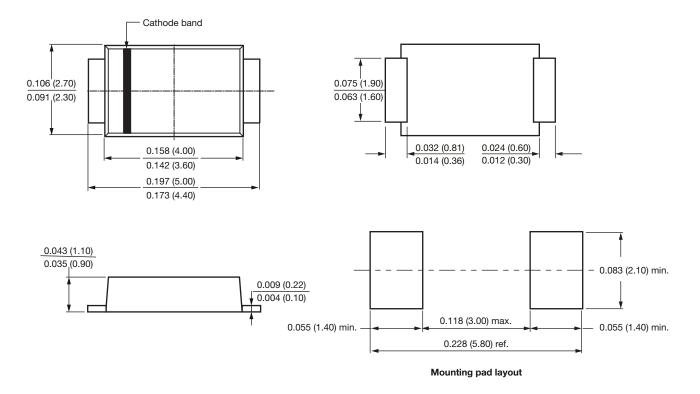


VSS8D3M12

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SlimSMAW (DO-221AD)





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